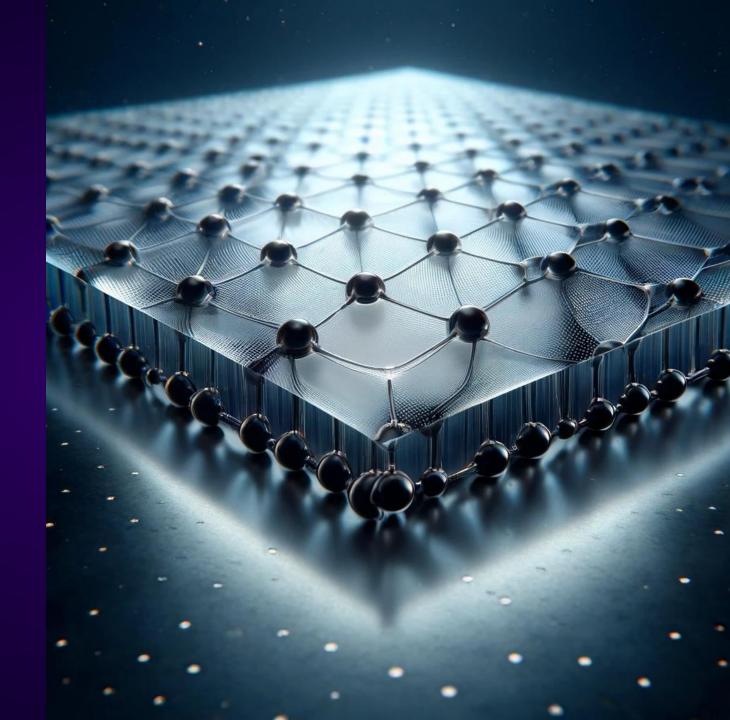


Transformational
Semiconductor Solutions
for Generative AI, Data
Centres, Cybersecurity
And Beyond

Presentation - October 2024







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This information in this presentation should be read in conjunction with the Indicative Terms in the Appendix and the Company's announcement dated 23 October 2024 (Announcement). The Company is optimistic about concluding the binding share purchase and for the Company proposed acquisition of 2D Generation. However, the Indicative Terms remain subject to negotiation by the parties and the execution of the binding share purchase agreement. Completion under the share purchase agreement will be subject to a number of conditions, including due diligence, as set out in Appendix. No binding agreement has been reached at this time and there is no certainty that the proposed acquisition will eventuate. The Indicative Terms in the appendix (and the Announcement) are preliminary, incomplete and non-binding and does not constitute a commitment to proceed with the proposed acquisition.

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Compelling AI and Semiconductor Thematic













Transformational Al and Semiconductor Opportunities

Surge in Defence and Cyber Security Activities

Reliance on Data Centres to Enable High **Performance Computing**

Leveraging Demand for Our Services

Sustained Revenue Growth

Proposed Acquisition of leading semiconductor IP business -2D Generation

Expansive growth in the defence and cyber security sectors has generated significant opportunities

Amplified by generative Al. driving demand for specialised semiconductor products and technological services

Our expertise in cyber threat protection, regulatory compliance, and IT security management is more relevant than ever

Continuously enhancing products to meet demand in high-growth sectors, fostering long-term client reliance in our data security ecosystem



Enabling the next generation of high-performance, energy-efficient solutions for AI and data centres.





2D Generation

2D Generation is partner in the EU's ConnectingChips consortium with research partners including NVIDIA, IMEC, Valeo, Applied Materials, NXP, and Unity







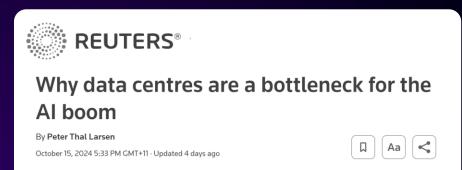




Rapid Industry Expansion

Dedicated to taking advantage of the explosive growth of Al and semiconductors by applying Al1's learnings in data centres, Al and cybersecurity:

- Advances are at breakneck speeds and investment is skyrocketing. The Al market will total USD 15.7 trillion by 2030 with an annual compound growth rate of 26.4% from 2020 to 2027. 1
- In 2023, the annual global spend on data centers surpassed US\$200 billion² with 2 new data centres being built every day.
- Demand for solutions powering Al is soaring.
- Compromising energy supply globally.
- https://www.pwc.com/gx/en/issues/artificial-intelligence/publications/artificial-intelligence-study.html https://www.gartner.com/en/newsroom/press-releases/2024-07-16-gartner-forecasts-worldwide-it-spending-to-grow-7-point-5-percent-in-2024



The Sydney Morning Herald

The \$5 trillion monster: Nvidia just became the world's most valuable company

Subrat Patnaik and Carmen Reinicke Updated June 19, 2024 - 6.22am, first published at 5.55am

WABC

Data centers fuel AI and crypto but could threaten climate, experts say

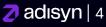
Data centers' energy usage is expected to soar in the coming years, experts say.

April 20, 2024, 8:08 PM









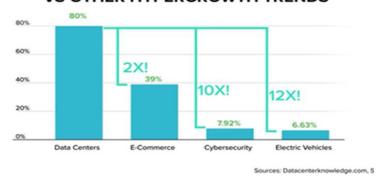




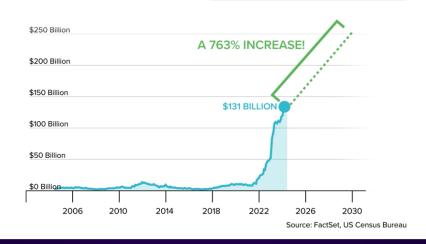


Why we need the next generation of semiconductor technology in three graphs

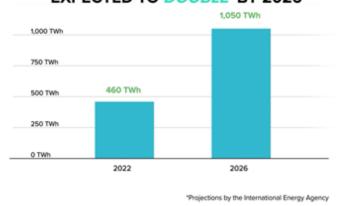
PROJECTED GROWTH RATE OF DATA CENTERS VS OTHER HYPERGROWTH TRENDS



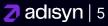
A PROJECTED **\$1 TRILLION** IS EXPECTED TO BE SPENT ON DATA CENTERS *IN THE NEXT 5 YEARS*



GLOBAL DATA CENTER ELECTRICITY DEMAND EXPECTED TO DOUBLE BY 2026



This explosion of data and generative AI being applied to it means more efficient semiconductors are critical for industry growth.

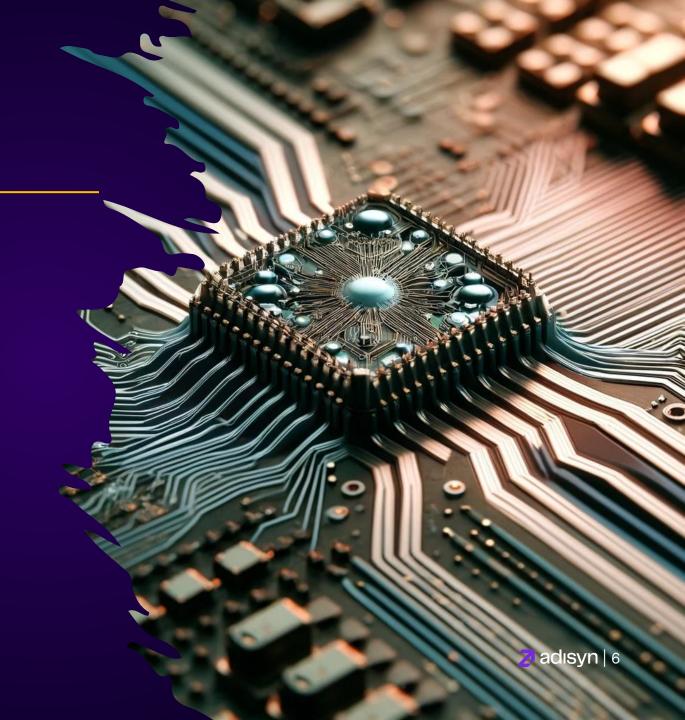


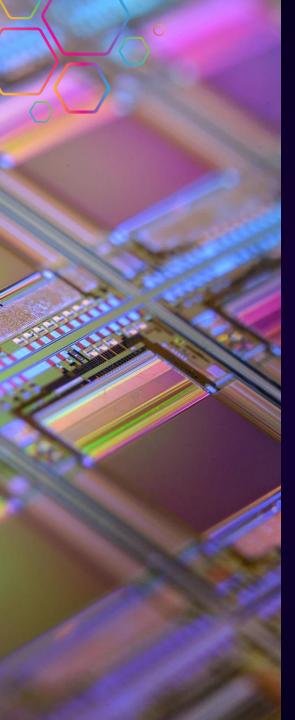


What is an 'Interconnect'?

2D Generation's innovative technology centres around the aim of improving the performance and capabilities of the interconnect.

- An interconnect in a semiconductor refers to the conductive pathways that connect different components or regions within an integrated circuit (IC).
- These interconnects are crucial for the functionality of the IC as they facilitate the flow of electrical signals between transistors, capacitors, resistors, and other elements on the chip.
- Interconnects can be made of various materials, typically metals like aluminium or copper, and they can be implemented in different layers within the semiconductor structure.
- As ICs have become more complex, with smaller and more densely packed features, the design and materials used for interconnects have evolved to address issues such as resistance, capacitance, and signal integrity but have reached scalability limitations.





Enabling 'More Moore'

"With each new technology generation, routing congestion and a dramatic signal delay (resulting from an increased resistancecapacitance (RC) product) become more and more problematic..."*

- For advanced process nodes, the 'Interconnect' is a bottleneck:
 - Limiting clock and data transfer rates... 'FORCED SPEED LIMITATION'
 - Consumes a lot of power... 'COMPETING FOR ELECTRICITY'
 - Major source of heat generation... 'ADVANCED PREFORMANCE CAN BE ACHIEVED. MANY MORE TRANSISTORS CAN BE ADDED'
- "To continue scaling beyond the 2nm node, major breakthroughs in interconnect and contact design, as well as process technologies, are necessary." (Applied Materials website)
- Graphene based solutions for the 'INTERCONNECT' are well defined, BUT UNTIL NOW THERE IS NO VIABLE SOLUTION
- From IMEC's paper on Graphene for interconnects in 2021:

 "While this study focuses on graphene transfer, a more 'elegant' way of depositing graphene would be direct growth on the metal template of interest. Growing high-quality graphene requires however high growth temperatures (900-1000°C) and can as such not be applied on interconnect-type of metals."

⁺ Moore's Law is the principle that the speed and capability of computers can be expected to double every two years, as a result of increases in the number of transistors a microchip can contain

<u> https://www.imec-int.com/en/articles/promise-hybrid-graphenemetal-structures-advanced-interconnects</u>

Atomic Layer Deposition

Despite efforts, significant breakthroughs in this domain are still elusive

- The Atomic Layer Deposition (ALD) market is experiencing substantial growth. Major industry
 players, such as ASM International NV (ASMI), Applied Materials Inc. (AMAT), Tokyo Electron
 Limited (TEL) and Lam Research Corporation (LAM), have dedicated R&D teams focusing on
 Plasma Enhanced Chemical Vapor Deposition (PECVD), particularly for graphene deposition.
- Enter 2D Generation. With its groundbreaking innovation enabling in-situ ALD graphene deposition at low temperatures, 2D Generation is positioned uniquely within the industry. This focus on graphene integration sets 2D Generation apart, presenting a disruptive potential that could reshape the landscape of semiconductor manufacturing.
- The interconnect field emerges as a critical technological barrier hindering industry progress. Overcoming this challenge is perceived as the "Holy Grail" within the industry, promising accelerated rates and continued miniaturisation. Industry giants recognize that the entity with a viable solution stands to gain a substantial competitive advantage.
- This technological breakthrough holds the potential to revolutionise production devices, enabling faster and more advanced chip manufacturing compared to competitors.

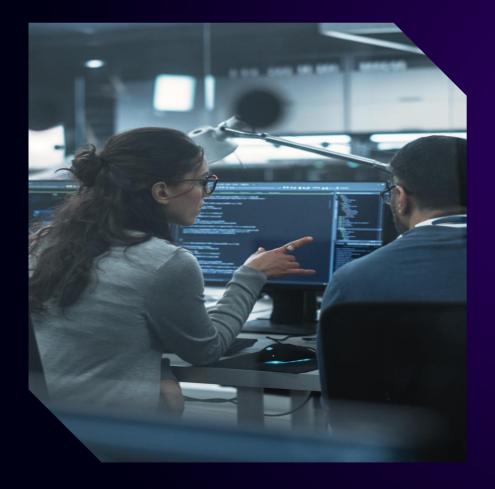


2D Generation's Advantages

- ✓ Unique and patented process
- ✓ Automic Layer Deposition (ALD) based
- ✓ Forming graphene directly on the wafer
- ✓ Use of patented precursors
- ✓ Low-temperature process at below 280°C (previously only possible at 1000 degrees) – a giant leap forward.
- ✓ Compatible with current manufacturing limitations fab friendly
- ✓ An addition of a tethering group is designed to increase adhesion to silicon oxide, metals, and other optional surfaces
- ✓ Can be applied using existing industrial processes and equipment no retooling.



unec



2D Generation's IMEC Agreement



Imec founded in 1984 is one of the world's leading R&D hubs for nano and digital technologies. Imec employs around 5,000 expert scientists from more than 95 countries, unique infrastructure that includes a 2.5billion-euro 300mm semiconductor pilot line. Among Imec's business partners are most of the manufacturers, suppliers, and fabless companies in the semiconductors industry including:



2D Generation has signed a strategic cooperation agreement with Imec to validate the company technology in two aspects:

- Physical tests of the graphene coating of several materials (metals and non-metals) and several usages (surfaces, structured wafers, and diffusion barrier).
- 2. Simulation to explore the benefits of the technology in a relevant context for product applications.

2DG's European Project – CONNECTINGCHIPS





ConnectingChips Collaboration

- It is accepted throughout the semiconductor world that the next generation of artificial intelligence capable chips are critical to advance Al. However, as it stands now, the semiconductor industry's catchery of 'more Moore's' is under threat.
- The advance to further miniaturisation, i.e. lower energy and less heat is being curtailed by the current limitations of the 'interconnector'.
- Interconnects are currently coated in metal, usually copper, gold, or aluminium. This inhibits miniaturization and the associated benefits. It has been known industry-wide for some time that replacing metal with graphene is a viable solution. However, this bonding process was only able to be done at 1000 degrees centigrade, basically cooking the chipset.
- Enter 2DG's simple and elegant solution. 2DG uses an Atomic Layer Disposition machine, or ALD, to bond graphene to interconnects
 at 300 degrees or less. This does not damage the chipset. The solution is recognised as critical to the industry, the semiconductor
 industry.
- It is so critical that 2D Generation is partnering with the likes of NVIDIA, Valeo, IMEC, Applied Minerals, NXP, and AIX-TRON via the ConnectingChips Undertaking, a program run in the EU for the semiconductor industry focused on the next generation of AI solutions.

2D Generation Key Objective's

- Leverages Graphene's exceptional properties to improve semiconductor technology.
- 2DG will develop pioneering low-temperature ALD techniques for depositing Graphene directly onto semiconductor materials.
- Enhances performance in interconnects, coatings, and capping layers, addressing impedance, resistivity, and heat dissipation challenges
- Leverage the relationships within the ConnectingChips consortium to the benefit of 2D Generation and Al1.

Working with the Best

- 7
- Key Objective "The CONNECTINGCHIPS ambition is to establish the next generation of AI computing and autonomous vehicles infrastructure based on SiP development."
- The high level objective of CONNECTINGCHIPS is the development of power efficient high performance electronic, photonic, power, and RF chips and System on Chips (SoC) and their integration into System in Package (SiP) modules.

Project Scope:

Total budget: 110M€

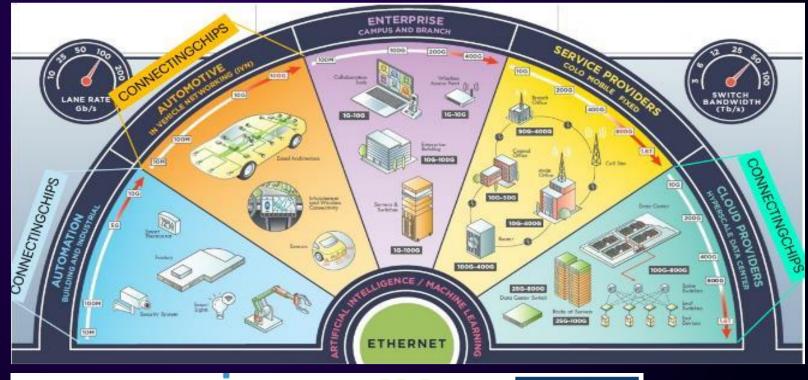
Total European grant: 32 M€

Additional grants from the country's innovation authorities – The Israeli Innovation Authority doubles the European grant.

Partners: 65 top companies and institutions (10 countries)

Start: Q1 2025

2D Generation requires a grant of 200K € from Horizon Europe Chips (IA) + grant of 200K € from the Israeli Innovation Authority (approved)

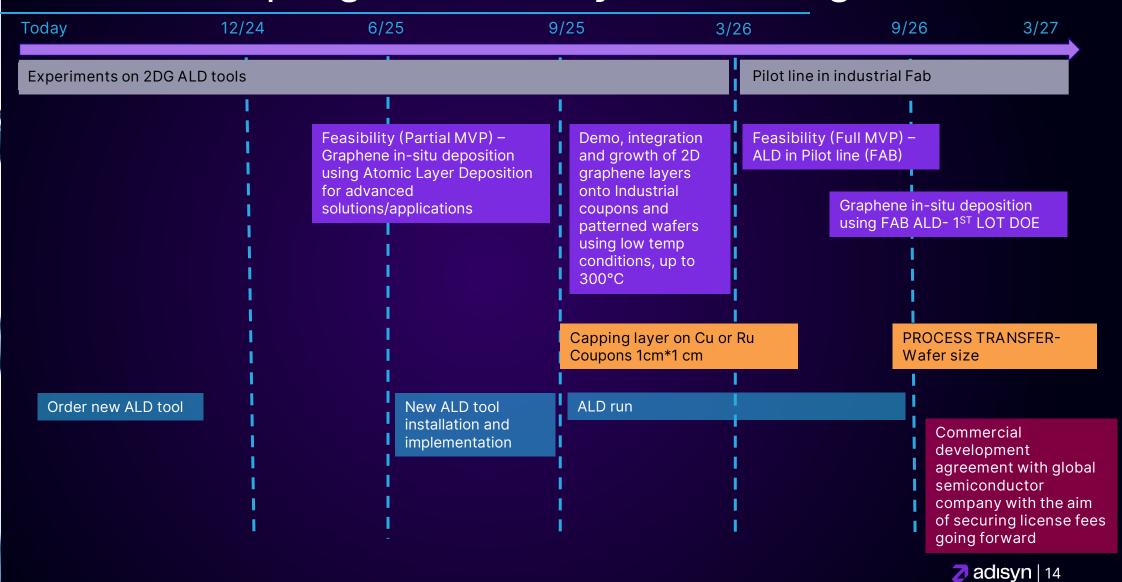








2DG Road Map: Significant Catalysts Delivering Value





Appendix: Intellectual Property

Four Patent Families:

- GRAPHENE COATED <u>NON-METALLIC</u> SURFACES, DEVICES AND METHOD THEREOF directed to the technologies used for conductive diffusion barrier, and other applications
- 2. GRAPHENE COATED <u>METALLIC</u> SURFACES, DEVICES AND METHOD OF MANUFACTURE THEREOF directed to the technologies used for conductive capping layer, and other applications
- 3. METHOD OF MANUFACTURE OF GRAPHENE COATED SURFACES BY ATOMIC OR MOLECULAR LAYER

 DEPOSITION directed to graphene manufacture by ALD
- 4. GRAPHENE METAL COMPOSITE directed to graphene layers interlayered with metal layers including coatings of patterned surfaces

Each patent application is directed to four aspects of the invention:

- 1. METHODS novel processes for manufacturing the graphene coated surfaces
- 2. MATERIALS unique proprietary materials used in each process
- 3. PRODUCT exhibiting unprecedented properties and qualities of surfaces coated by graphene
- DEVICES made of the product including interconnects, nano- electro mechanical devices and
 transparent electrodes

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2D Generation's Strong Technological Team Compliments AI1





ARYE KOHAVI CEO

Arye is an Israeli entrepreneur and innovator. He was the founder, president & Co-CEO of Water-Gen, which develops water-from-air and air dehumidification technologies. Kohavi holds a MBA (Finance) and a BA in Economics and Accounting, both from the Hebrew University in Jerusalem.

- Arye has been chosen as one of the world's 100 Leading Global Thinkers, and one of the world's top innovators of 2014, by "Foreign Policy" magazine.
- Water-Gen, founded by Arye, was chosen as one of the World's 50 Most Innovative Companies, by "Fast Company" magazine.
- As part of Israel's 70th anniversary celebrations, the Israeli Ministry of Economy and Ynet readers chose Water-Gen as one of the "Nine Greatest Israeli Inventions of All Times".
- Water-Gen's Genny was chosen as one of the world's 100 Best Inventions of year 2019, by TIME magazine.



MIRI KISH DAGAN VP R&D

Miri Kish - Dagan was the VP R&D and the CTO of Raicol crystals that specializes in the manufacture of high-quality nonlinear optical crystals and electro-optic devices. Miri led the development from inception to prototype in semiconductors, medical, military, and space applications.

- Miri has over 19 years of experience with engineering processing, technologies and R&D management in fabrication and tool installation. Prior to Raicol, Miri served at Suron as VP of R&D engineering, and in various positions at Tower semiconductors.
- Winner of the Pioneering Women Award for groundbreaking achievements in the high-tech sector given to her by the Israeli Hi-Tech Association and the Manufacturers Association of Israel.
- Miri received her MSc and BSc in Material Engineering from Ben-Gurion University in Israel.



PAUL RICH TECHNOLOGY LEADER

Paul Rich has more than 35 years of experience in the semiconductor industry.

- Paul was the Vice President for Technology and Engineering at SPTS Technologies, where he managed the product development team until December 2022. SPTS develops and manufactures advanced wafer processing solutions for the world's leading semiconductor and microelectronic device manufacturers.
- Mr. Rich graduated from Bath University in 1987 with a B.Sc in Physics. He has published numerous technical articles and has several patents relating to plasma processing.

2DG's World Class Advisory Board



EPHIE KOLTIN

Ephie has vast management experience in senior executive positions; integration of complex systems within – development, operations and business strategy, in Israel and abroad.

23 years at TowerJazz Semiconductors as Business Unit Manager, VP Business Development & Strategic Marketing, Fab General Management, and COO.

2017 - PRESENT Arkal Automotive, CEO

2015 -2017 Synergy cables, CEO

2014 –2016 Phoenicia Flat Glass Industries, Active Chairman

1993 – 2014 TowerJazz Semiconductors, From Process engineer to COO



KEVIN CROFTON

Kevin has many years of experience in the semiconductor industry. Today Kevin is the CEO of the Comet Group.

He has established himself in the semiconductor industry in numerous awards and positions such as the author of many important technical articles, member and Vice Chairman of the SEMI International Board of Directors and winner of the MEMS Industry CEO of the Year 2013.

2020 – 2022 Comet Group (traded in SIX Swiss Stock Exchange), CEO

2017 – 2020 Orbotech, Corporate EVP

2004 – 2014 SPTS Technologies (UK), currently part of KLA. Several roles include EVP & Chief Operating Officer. 2014 - Present President





Thank you

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Michael Shaw-Taylor – Corporate Advisor mst@sandtoncapital.com.au

2D GENERATION / ADISYN LTD (ASX:AI1)

